

CORRECTION

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Correction: Dual-defect surface engineering of bimetallic sulfide nanotubes towards flexible asymmetric solid-state supercapacitors

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Correction for 'Dual-defect surface engineering of bimetallic sulfide nanotubes towards flexible asymmetric solid-state supercapacitors' by Ling Kang *et al.*, *J. Mater. Chem. A*, 2020, DOI: 10.1039/d0ta08979f.

The authors regret that an incorrect version of Fig. 5c was provided in the published article. The correct version of Fig. 5c is provided here:

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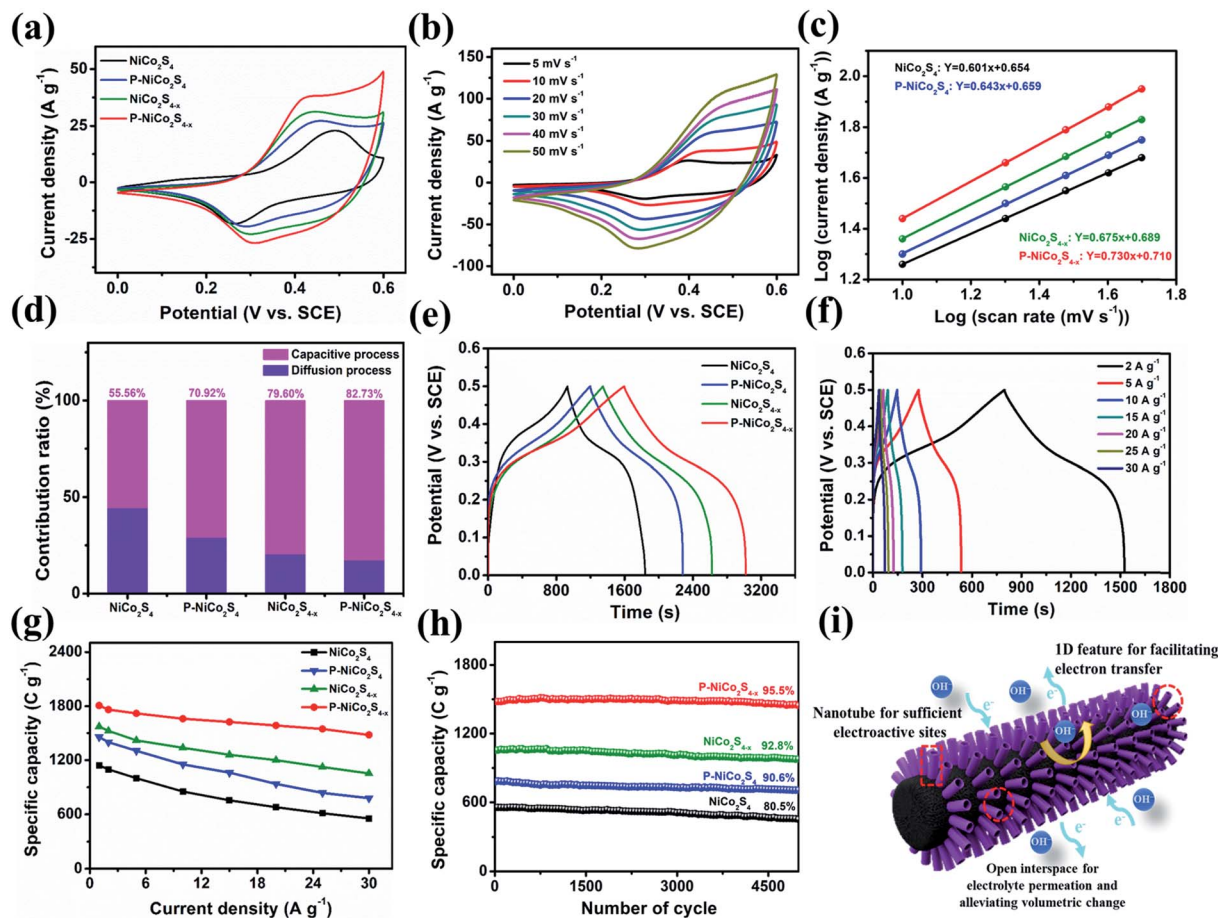


Fig. 5 (a) Comparison of the CV curves of NiCo₂S₄, P-NiCo₂S₄, NiCo₂S_{4-x}, and P-NiCo₂S_{4-x} at a scan rate of 10 mV s⁻¹. (b) CV curves of P-NiCo₂S_{4-x} at different scan rates. (c) Determination of the *b*-values of NiCo₂S₄, P-NiCo₂S₄, NiCo₂S_{4-x} and P-NiCo₂S_{4-x} from the current densities of cathodic peaks using the power law. (d) Histogram illustrating the ratio of capacitive and diffusive contributions to capacitance at 10 mV s⁻¹. (e) Comparison of the GCD curves of NiCo₂S₄, P-NiCo₂S₄, NiCo₂S_{4-x} and P-NiCo₂S_{4-x} at a current density of 1 A g⁻¹. (f) GCD curves of P-NiCo₂S_{4-x} obtained at different current densities. (g) Specific capacities obtained at various current densities. (h) Cycling performances of NiCo₂S₄, P-NiCo₂S₄, NiCo₂S_{4-x} and P-NiCo₂S_{4-x} at a high current density of 30 A g⁻¹. (i) Schematic illustrating the structural advantages of P-NiCo₂S_{4-x} nanotubes in terms of electrochemical reactivity.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

